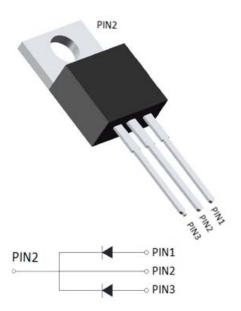




Schottky Diodes



Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

• Package: TO-220AB

Molding compound meets UL 94 V-0 flammability

rating, RoHS-compliant

• Terminals: Tin plated leads, solderable per J-STD-

002 and JESD22-B102
• Polarity: As marked

■Maximum Ratings (Ta=25°C Unless otherwise specified)

= waximum ratings (1a 25 © offices outstweet opening)					
PARAMETER	SYMBOL	UNIT	MBR2045CTS		
Device marking code			MBR2045CTS		
Repetitive Peak Reverse Voltage	VRRM	V	45		
Average Rectified Output Current @60Hz sine wave, R-load, Ta=25℃	IO	Α	20		
Surge(Non-repetitive)Forward Current @60H _Z half sine-wave,1 cycle, T _a =25°C	IFSM	Α	130		
Current Squared Time @1ms≤t<8.3ms Tj=25℃,	l ² t	A ² s	70		
Storage Temperature	T _{stg}	$^{\circ}$	-55 ~ + 150		
Junction Temperature	Tj	$^{\circ}$	-55 ~ +150		

■Electrical Characteristics (Ta=25°C Unless otherwise specified)

==ioomiomiomiomiomiomiomiomiomiomiomiomiom				
PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR2045CTS
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=10.0A	0.65
Maximum DC reverse current at rated DC blocking voltage per diode IRRM2	A	VRM=VRRM T _a =25°C	0.2	
		mA ·	VRM=VRRM T _a =125°C	100

Note1:Pulse test:300uS pulse widh,1% duty cycle

Note2:Pulse test:pulse widh 40mS

MBR2045CTS

Thermal Characteristics $(T_a=25^{\circ}\mathbb{C} \text{ Unless otherwise specified})$

PARAMETER		SYMBOL UNIT		MBR2045CTS	
Thermal Resistance	Between junction and case	R _{θJ-C}	°C /W	2.0	

■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR2045CTS	Approximate 1.9	50	1000	5000	Tube

■Characteristics (Typical)

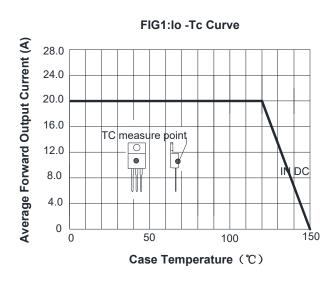
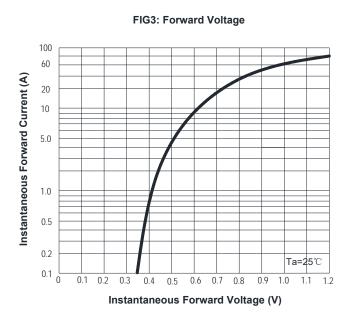
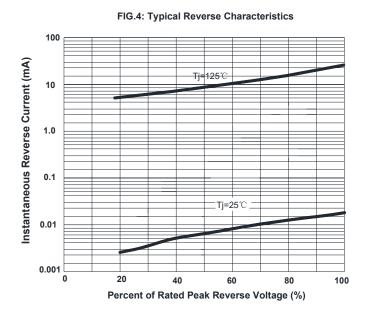


FIG2:Surge Forward Current Capability 170 Peak Forward Surge Current (A) 150 130 8.3ms Single Half Sine-Wave 110 JEDEC Method 90 70 50 2 20 5 10 50 100

Number of Cycles

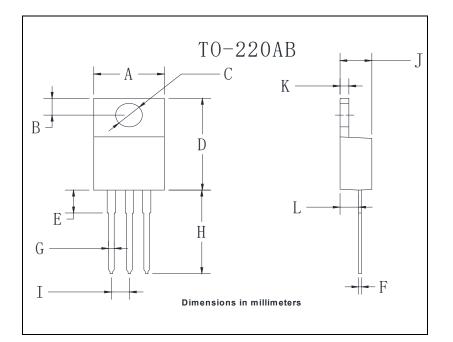






MBR2045CTS

■Outline Dimensions



TO-220AB				
Dim	Min	Max		
Α	9.95	10.35		
В	2.55	2.95		
С	3.8	4.0		
D	14.95	15.25		
E	3.75	4.25		
F	0.26	0.5		
G	0.68	0.94		
Н	13.4	13.9		
I	2.35	2.65		
J	4.38	4.78		
K	1.14	1.4		
L	2.37	2.79		



MBR2045CTS

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